

LS4558N

DUAL HIGH PERFORMANCE OPERATIONAL AMPLIFIER

- SINGLE OR SPLIT SUPPLY OPERATION
- LOW POWER CONSUMPTION
- HIGH UNITY GAIN BANDWIDTH
- NO CROSSOVER DISTORSION
- NO POP NOISE
- SHORT-CIRCUIT PROTECTION
- HIGH CHANNEL SEPARATION

DESCRIPTION

The LS4558N is a high performance dual operational amplifier with frequency and phase compensation built into the chip. The internal phase compensation allows stable operation as voltage follower in spite of its high gain-bandwidth products. The circuit presents very stable electrical characteristics over the entire supply voltage range and the specially designed input stage allow the LS4558N to be used

SCHEMATIC DIAGRAM (one section)

in low noise audio signal processing application. The optimized class AB output stage completely eliminates crossover, distorsion, under any load conditions, has large source and sink capacity and is short-circuit protected.





CONNECTION DIAGRAM (top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
Vs	Supply Voltage		± 18	V
V ₁	Input Voltage	± Vs		
Vi	Differential Input Voltage		$\pm (V_{s} - 1)$	V
Ptot	Power Dissipation at T _{amb} = 70 °C	Minidip Micropackage	665 400	mW mW
Top	Operating Temperature		0 to 70	°C
T	Junction Temperature		150	°C
Tstg	Storage Temperature		- 55 to 150	°C

THERMAL DATA

		Minidip	SO-8
R _{th j-amb}	Thermal Resistance Junction-ambient	120 °C/W	200 °C/W

TYPICAL APPLICATIONS

Balanced Input Audio Preamplifier.



DC Coupled Low-pass Active Filter (f = 1 KHz, $G_V = 6 \text{ dB}$).





Symbol	Para	meter	Test Conditions		Min.	Тур.	Max.	Unit
I _s	Supply Current	t (*)				1	2	mA
I _b	Input Bias Curi	rent				50	500	nA
			T _{min} < T _{op} < T	max			800	nA
R,	Input Resistan	се	f = 1 KHz		0.3	1		MΩ
Vos	Input Offset Voltage		R _g ≤ 10 KΩ			0.5	5	mV
			$R_g \le 10 \text{ K}\Omega$ $T_{min} < T_{op} < T$	max			7.5	mV
los	Input Offset Current					20	200	nA
			T _{min} < T _{op} < T	max			500	nA
lsc	Output Short C	Circuit Current				23		mA
Gv	Large Signal Open Loop R _L = 2 KΩ Voltage Gain		86	100		dB		
В	Gain-bandwidt	h Product	f = 20 KHz		2	3		MHz
e _N	Total Input Noi	ise Voltage	f = 1 KHz	$R_{g} = 50 \Omega$ $R_{g} = 1 K\Omega$ $R_{g} = 10 K\Omega$		8 10 18	15	nV √Hz
θ _N	Popcorn Noise		B = 1 Hz to 1 K R _g = 10 KΩ t = 10 sec	ίHz			10	μV Peak
d	Distortion		$G_v = 20 \text{ dB}$ $V_o = 2 \text{ Vpp}$	R _L = 2 KΩ f = 1 KHz		0.03		%
Vo	Output Voltage Swing		R _L = 2 KΩ			± 13		V
Vo	Large Signal Voltage Swing		$R_{L} = 10 \text{ K}\Omega$ $f = 10 \text{ KHz}$			28		Vpp
	Transient Response	Rise Time	V, = 20 mV	B ₁ = 2 KΩ		0.13		μS
		Overshoot	C _L = 100 pF		5		%	
SR	Slew Rate		Unity Gain R _L = 2 KΩ		0.8	1.5		V/µs
CMR	Common Mode Rejection		$V_i = 10 V$ $T_{min} < T_{op} < T$	max	70	90		dB
SVR	Supply Voltage Rejection		$V_i = 1 V$ $T_{min} < T_{op} < T$	f = 100 Hz	80	100		dB
CS	Channel Separation		f = 10 KHz	$R_g = 1 K\Omega$		105		dB

ELECTRICAL CHARACTERISTICS (V_s = \pm 15 V, T_{amb} = 25 °C, unless otherwise specified)

(*) Both amplifiers.

Figure 1 : Open Loop Frequency and Phase Response.







Figure 5 : Output Voltage Swing vs. Load Resistance.



Figure 2 : Open Loop Gain vs. Ambient Temperature.



Figure 4 : Large Signal Frequency Response.



Figure 6 : Total Input Noise vs. Frequency.



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Figure 7 : Channel Separation.







APPLICATION INFORMATION



Figure 10 : Mike/Line Preamplifier for Audio Mixers (0 dB to 60 dB continuously variable gain).

ble in a logarithmic mode from 0 dB to 60 dB in the audio band.

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Figure 12 : Very Low-noise Mike Preamplifier (G_V = 40 dB).



Figure 13 : Balanced Input Audio Preamplifier.



Figure 15 : Frequency Response of the Highpass Filter of Figure 14.

Figure 14 : 20 Hz to 200 Hz Variable High-pass Filter (Gv = 3 dB).



Figure 16 : DC Coupled Low-pass Active Filter (f = 1 KHz, Gv = 6 dB).



Figure 17 : Switchable HP-LP Audio Filter.



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Figure 18 : Subsonic or Rumble Filter (GV = 0 dB).



Figure 19 : High-cut Filter (Gv = 0 dB).



Figure 20 : Fifth Order 3.4 KHz Low-pass Butterworth Filter.



For $f_c = 3.4$ KHz and RI = R1 = R2 = R3 = R4 = 10 K Ω , we obtain :

C1 =
$$1.354 \cdot \frac{1}{R} \cdot \frac{1}{2\pi f_c} = 6.33 \text{ nF}$$

C1 = $0.421 \cdot \frac{1}{R} \cdot \frac{1}{2\pi f_c} = 1.97 \text{ nF}$
C1 = $1.753 \cdot \frac{1}{R} \cdot \frac{1}{2\pi f_c} = 8.20 \text{ nF}$

C1 = 0.309
$$\cdot \frac{1}{R} \cdot \frac{1}{2 \pi f_c}$$
 = 1.45 nF
C1 = 3.325 $\cdot \frac{1}{R} \cdot \frac{1}{2 \pi f_c}$ = 15.14 nF

The attenuation of the filter is 30 dB at 6.8 KHz and better than 60 dB at 15 KHz.







This is a 6-pole Chebychev type with \pm 0.25 dB ripple in the passband. A decoupling stage is used to avoid the influence of the input impedance on the filter's characteristics. The attenuation is about 55 dB at 710 Hz and reaches 80 dB at 1065 Hz. The in band attenuation is limited in practice to the \pm 0.25 dB ripple and does not exceed 0.5 dB at 0.9 fc.

